

# Nature of magnetic field and angular dependencies of the critical current density in epitaxial HTS $\text{YBa}_2\text{Cu}_3\text{O}_{7-\delta}$ films

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## Abstract

Out-of-plane edge dislocations (mean 2D density is  $10^{11}$  lines/cm<sup>2</sup>) in low-angle tilt domain boundaries of single-crystalline YBCO films are shown to play a crucial role in  $J_c(H\|c, T)$ -behavior and  $J_c$  angular dependence. Dislocation cores and their vicinity, where  $T_c$  is locally suppressed, are shown to provide an extremely strong pinning force resulting in  $J_c(77 \text{ K}) \approx 2 \cdot 10^6 \text{ A/cm}^2$ . Peculiarities of  $J_c(H\|c)$  are found in the low field range. A simple model of pinning by dislocation domain boundaries is developed. The model consistently describes the  $J_c(H\|c, T)/J_c(0, T)$ -dependencies, accounting for the fraction of vortices pinned by dislocations. Angular dependencies of  $J_c$  in rotating magnetic field were measured by four-probe transport technique. A satisfactory agreement with theoretically predicted behavior has been found.

**Key words:** high- $T_c$  superconductivity; epitaxially grown thin films; pinning by edge dislocations

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Epitaxially grown thin films of  $\text{YBa}_2\text{Cu}_3\text{O}_{7-\delta}$  (YBCO) high-temperature superconductor (HTS) exhibit high  $J_c(77 \text{ K})$ , that is two orders of magnitude higher than the critical current in YBCO bulk materials. High average density (up to  $10^{11}$  lines/cm<sup>2</sup>) of growth-induced linear defects (dislocations) was revealed in YBCO films by high resolution electron microscopy [1-3]. The electromagnetic behavior of YBCO films, in particular  $J_c$ , associated with *out-of-plane* dislocations in a network of tilt low-angle boundaries (LABs) forming mosaic domains [1-3], was studied in a number of papers [4-8]. Typical  $J_c(H\|c)$ -dependencies consist of a low-field plateau region followed by a monotonic decline fitted usually by a power law  $J_c(H\|c) \propto H^{-q}$ , where  $q$  is about 0.5. In the present work, the  $J_c(H\|c, T)$  behavior for pulse-laser deposited (PLD) YBCO films is studied at low fields. It is shown that the dependence just above the plateau is well fitted by a logarithmic rather than a power law.

A theoretical model, which allows to fit  $J_c(H\|c, T)$ -curves, is developed.  $J_c$  angular dependence in a tilted magnetic field demonstrates a remarkable peak at  $H\|c$ . This peak is supposed to be an evidence of contribution of pinning by out-of-plane edge dislocations. A simple model of tilted vortex pinning on such linear defects is proposed.

Measurements of  $J_c(H\|c, T)$  in PLD YBCO films on  $\text{LaAlO}_3$  (100) substrates were carried out in the temperature range  $T_c > T > 77 \text{ K}$  by AC magnetic susceptibility technique. The normalized dependencies  $J_c(H\|c, T)/J_c(0, T)$  are presented in Fig. 1. The dependencies have a low-field plateau region  $0 \leq H \leq H_m(\tau)$  and a crossover at  $H = H_m(\tau)$  to the falling down behavior, that can be universally fitted at intermediate fields by the expression:  $J_c(H\|c, T)/J_c(0, T) = \alpha \log H^*(\tau)/H$ , where  $\tau = 1 - T/T_c$ ,  $H^*(\tau) = H_m(\tau)e^{1/\alpha}$  is proportional to  $\tau$ , and  $\alpha$  is a weakly temperature dependent coefficient ( $\alpha \approx 0.19 - 0.24$ ).

The developed  $J_c$ -limitation model supposes vortex

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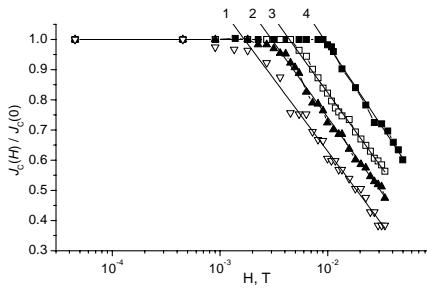


Fig. 1. Normalized  $J_c(H)/J_c(0)$ -dependencies: filled squares - 77 K; open squares - 80 K; filled triangles - 83 K; open triangles - 86 K. Solid lines 1-4 correspond to the equation  $y = \alpha \log H^*(\tau)/H$  with  $\alpha$  and  $H^*$  being 0.208 and 0.21 T; 0.215 and 0.31 T; 0.215 and 0.46 T; 0.234 and 0.64 T, respectively.

depinning from out-of-plane edge dislocations, which form LABs surrounding a multitude of mosaic domains with the mean size  $\langle L \rangle$ , slightly misoriented to each other.  $J_c(H, \tau)$  is shown to be determined by the fraction of pinned vortices in the distorted vortex line lattice (VLL). The critical displacement  $\delta(H, \tau)$  for a vortex in 2D disordered VLL to be pinned is found from the condition  $|\varepsilon_{pin}| \geq C_{66}\delta^2$ , where  $\delta$  is a displacement from equilibrium position in VLL,  $\varepsilon_{pin}$  is the energy of core-pinning and  $C_{66}$  is the elastic shear modulus of VLL.  $J_c(H, \tau)$  is expressed through  $\delta(H, \tau)$  and parameters of the size distribution function  $W(L)$  of the area occupied by domains.  $J_c(h \parallel c, T)/J_c(0, T)$  dependencies were calculated for the case of square domains with  $W(L)$  being a statistical  $\Gamma$ -distribution [8]. The model reproduces experimentally observed scaling  $J_c(H, \tau) \propto (\tau/H)^{1/2}$  at the logarithmic region as well as the values of its slope  $\alpha$ . The details of this model and comparison with experiments have been published elsewhere [9].

The critical current density  $J_c$  in epitaxial films of cuprate superconductors with the  $\bar{c}$ -axis oriented perpendicular to the substrate in applied magnetic field  $\bar{H}$  exhibits a highly anisotropic dependence on the angle  $\theta$  between  $\bar{H}$  and  $\bar{c}$ . Such dependencies were measured by the four-probe transport current technique for several YBCO films of different thickness  $d$ . The films were deposited with a use of two crossed beams pulse Nd/YAG lasers. Single crystalline  $\text{LaAlO}_3$  (100) substrates were used. The obtained  $J_c(\theta)$ -dependencies are shown in Fig. 2.

There are two peaks on the  $J_c(\theta)$  curves at  $\theta = 0$  ( $\bar{H} \parallel \bar{c}$ ) and at  $\theta = 90^\circ$  ( $\bar{H} \perp \bar{c}$ ). This dependence is apparently indicative of the existence of two pronounced systems of extended defects (dislocations) oriented along the  $\bar{c}$ -axis and in the  $ab$ -plane, and of the efficiency of pinning at such defects. The simplest model [10] of single-particle core pinning at  $\delta$ -function dislo-

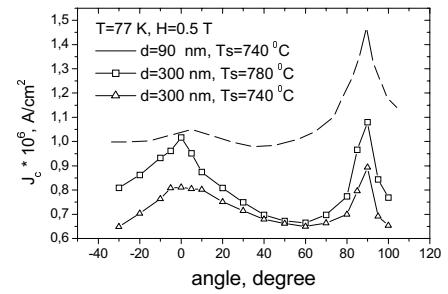


Fig. 2. Experimentally measured  $J_c(\theta)$  curves for pulse-laser deposited YBCO films on (100)  $\text{LaAlO}_3$  substrates.

cation core with the potential  $U_{pin}(r) = U_0 \pi r_0^2 \delta^2(r)$  in a tilted magnetic field has been shown to describe correctly the experimental  $J_c(\theta)$  dependencies in the cuprate epitaxial films.

In a summary, the model of vortex pinning by a dislocation domain LABs network in YBCO quasi-single-crystalline epitaxially grown films is shown to describe consistently the  $J_c(H \parallel c, T)/J_c(0, T)$ -dependencies with logarithmic regions. The simplest model of single-particle core pinning at dislocation cores in low tilted magnetic fields gives a qualitatively correct description of the orientational dependencies of pinning force and critical current.

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